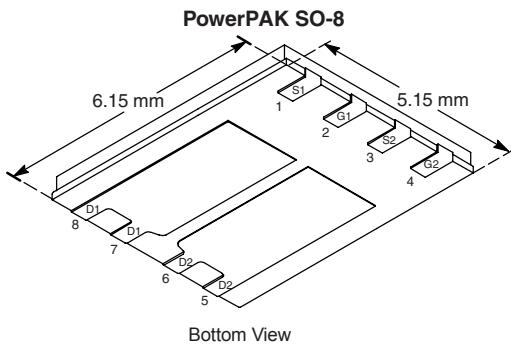


## Dual P-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY			
$V_{DS}$ (V)	$R_{DS(on)}$ ( $\Omega$ )	$I_D$ (A)	$Q_g$ (Typ.)
- 30	0.020 at $V_{GS} = - 10$ V	- 10.9	49
	0.031 at $V_{GS} = - 4.5$ V	- 8.8	



**Ordering Information:** Si7945DP-T1-E3 (Lead (Pb)-free)  
Si7945DP-T1-GE3 (Lead (Pb)-free and Halogen-free)

### FEATURES

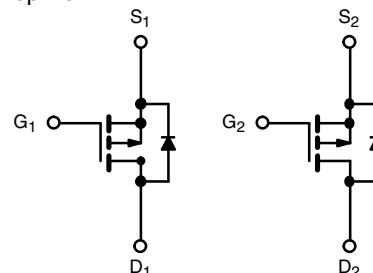
- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET® Power MOSFETs
- New Low Thermal Resistance PowerPAK® Package with Low 1.07 mm Profile



**RoHS**  
COMPLIANT  
**HALOGEN**  
**FREE**  
Available

### APPLICATIONS

- Battery and Load Switching
  - Notebook PCs
  - Game Systems
  - Set-Top Box



P-Channel MOSFET      P-Channel MOSFET

### ABSOLUTE MAXIMUM RATINGS $T_A = 25$ °C, unless otherwise noted

Parameter	Symbol	10 s	Steady State	Unit
Drain-Source Voltage	$V_{DS}$	- 30		V
Gate-Source Voltage	$V_{GS}$	$\pm 20$		
Continuous Drain Current ( $T_J = 150$ °C) <sup>a</sup>	$I_D$	- 10.9	- 7.0	A
$T_A = 70$ °C		- 8.7	- 5.6	
Pulsed Drain Current	$I_{DM}$	- 30		
Continuous Source Current (Diode Conduction) <sup>a</sup>	$I_S$	- 2.9	- 1.2	
Maximum Power Dissipation <sup>a</sup>	$P_D$	3.5	1.4	W
$T_A = 70$ °C		2.2	0.9	
Operating Junction and Storage Temperature Range	$T_J, T_{stg}$	- 55 to 150		
Soldering Recommendations (Peak Temperature) <sup>b, c</sup>		260		°C

### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient <sup>a</sup>	$t \leq 10$ s	$R_{thJA}$	26	35
	Steady State		60	85
Maximum Junction-to-Case (Drain)	$R_{thJC}$	2.5	3.1	

Notes:

- Surface Mounted on 1" x 1" FR4 board.
- See Solder Profile ([www.vishay.com/ppg?73257](http://www.vishay.com/ppg?73257)). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

**SPECIFICATIONS**  $T_J = 25^\circ\text{C}$ , unless otherwise noted

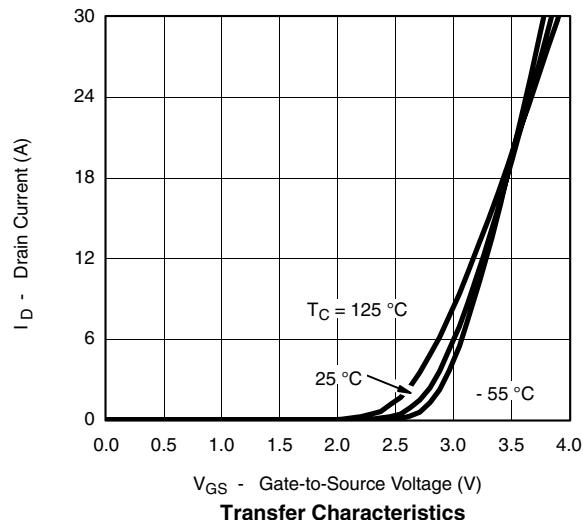
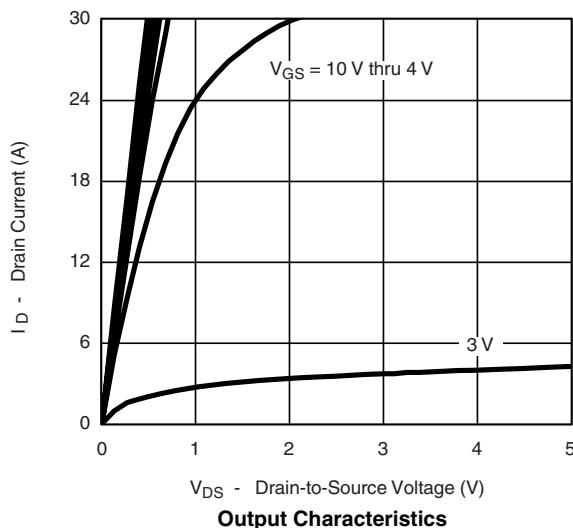
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
<b>Static</b>						
Gate Threshold Voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}$ , $I_D = -250 \mu\text{A}$	-1.0		-3.0	V
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0 \text{ V}$ , $V_{GS} = \pm 20 \text{ V}$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -30 \text{ V}$ , $V_{GS} = 0 \text{ V}$		-1		$\mu\text{A}$
		$V_{DS} = -30 \text{ V}$ , $V_{GS} = 0 \text{ V}$ , $T_J = 55^\circ\text{C}$			-5	
		$V_{DS} \leq -5 \text{ V}$ , $V_{GS} = -10 \text{ V}$	-30			
On-State Drain Current <sup>a</sup>	$I_{D(\text{on})}$	$V_{GS} = -10 \text{ V}$ , $I_D = -10.9 \text{ A}$		0.016	0.020	$\Omega$
		$V_{GS} = -4.5 \text{ V}$ , $I_D = -8.8 \text{ A}$		0.025	0.031	
		$V_{DS} = -15 \text{ V}$ , $I_D = -10.9 \text{ A}$		26		
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	$I_S = -2.9 \text{ A}$ , $V_{GS} = 0 \text{ V}$		-0.8	-1.2	V
<b>Dynamic<sup>b</sup></b>						
Total Gate Charge	$Q_g$	$V_{DS} = -15 \text{ V}$ , $V_{GS} = -10 \text{ V}$ , $I_D = -10.9 \text{ A}$		49	74	nC
Gate-Source Charge	$Q_{gs}$			7.3		
Gate-Drain Charge	$Q_{gd}$			13		
Turn-On Delay Time	$t_{d(\text{on})}$	$V_{DD} = -15 \text{ V}$ , $R_L = 15 \Omega$ $I_D \equiv -1 \text{ A}$ , $V_{GEN} = -10 \text{ V}$ , $R_g = 6 \Omega$		15	25	ns
Rise Time	$t_r$			15	25	
Turn-Off Delay Time	$t_{d(\text{off})}$			130	200	
Fall Time	$t_f$			80	120	
Source-Drain Reverse Recovery Time	$t_{rr}$	$I_F = -2.9 \text{ A}$ , $di/dt = 100 \text{ A}/\mu\text{s}$		85	130	

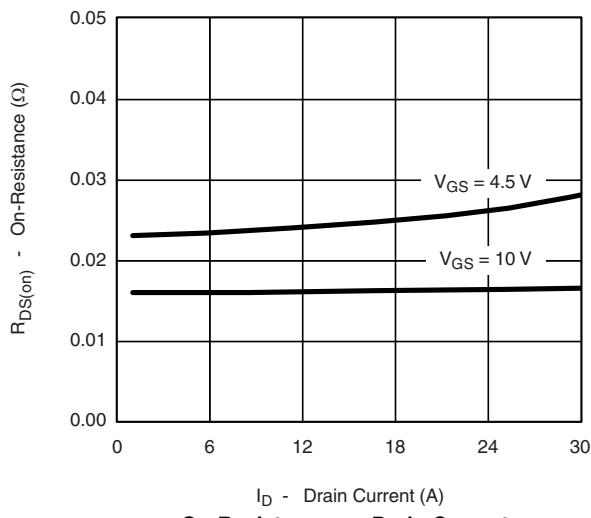
Notes:

a. Pulse test; pulse width  $\leq 300 \mu\text{s}$ , duty cycle  $\leq 2\%$ .  
b. Guaranteed by design, not subject to production testing.

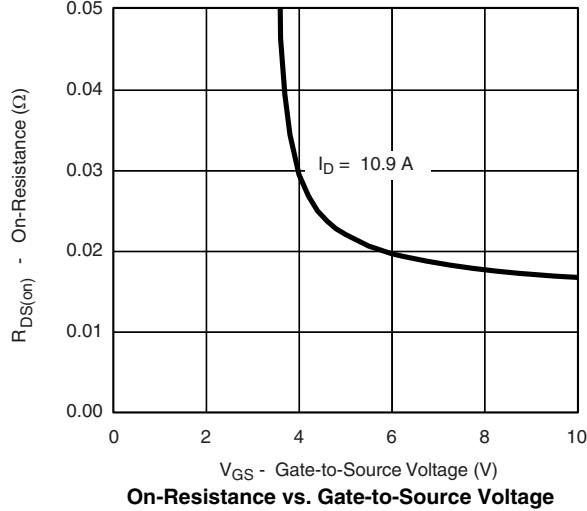
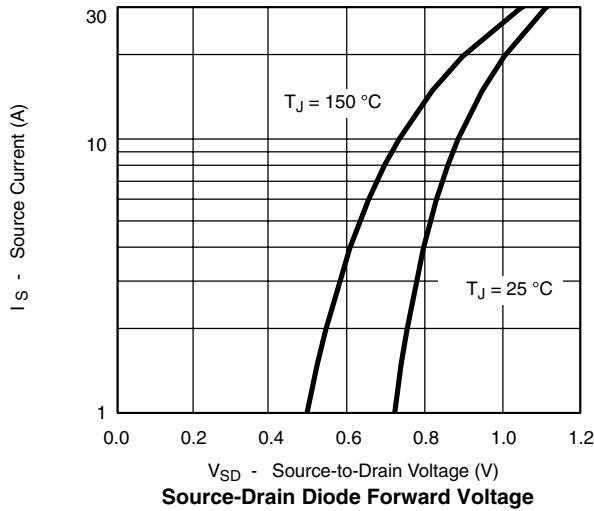
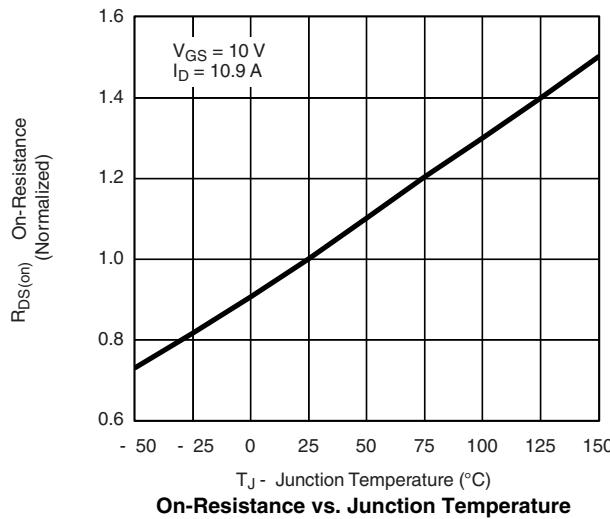
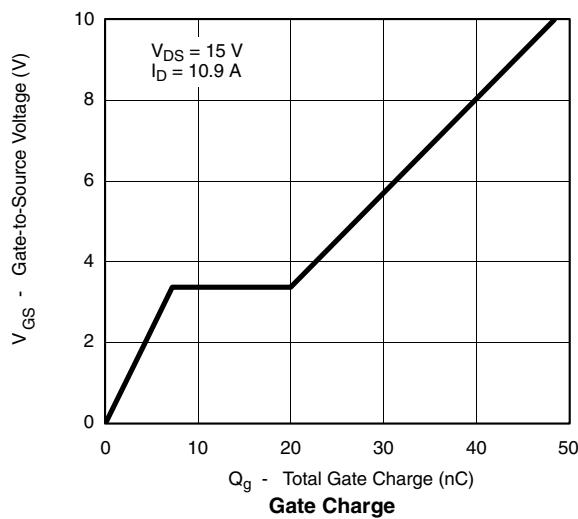
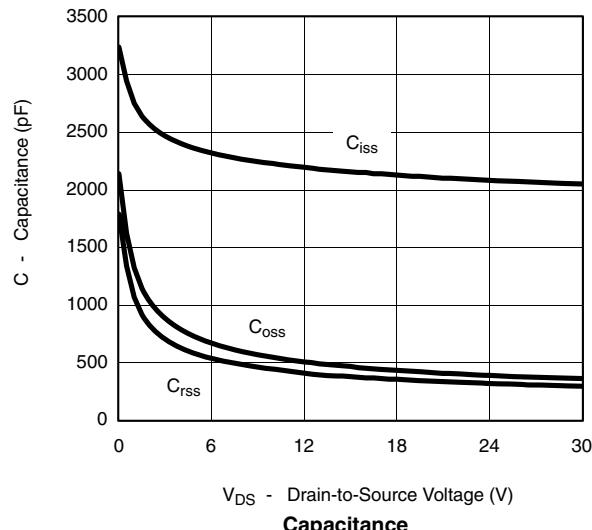
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

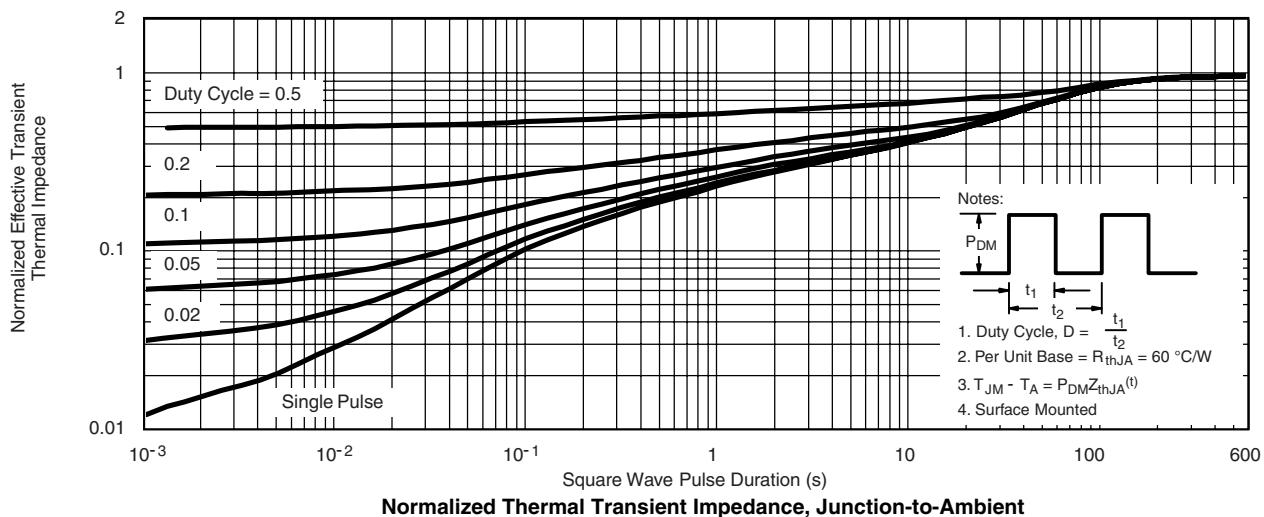
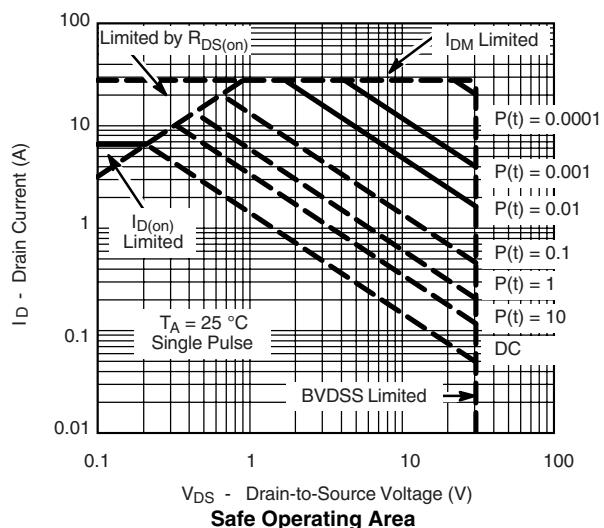
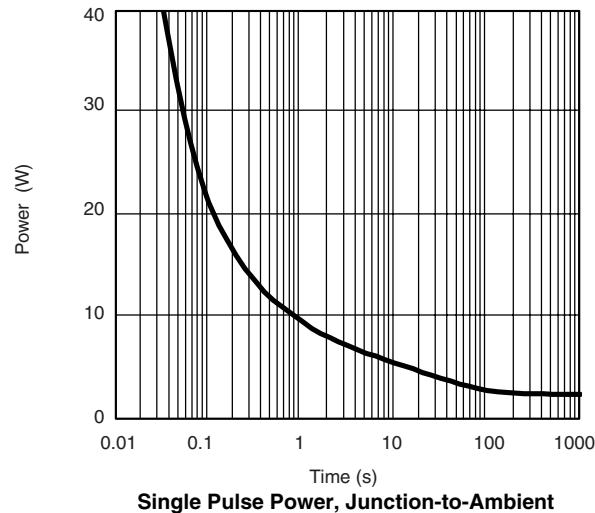
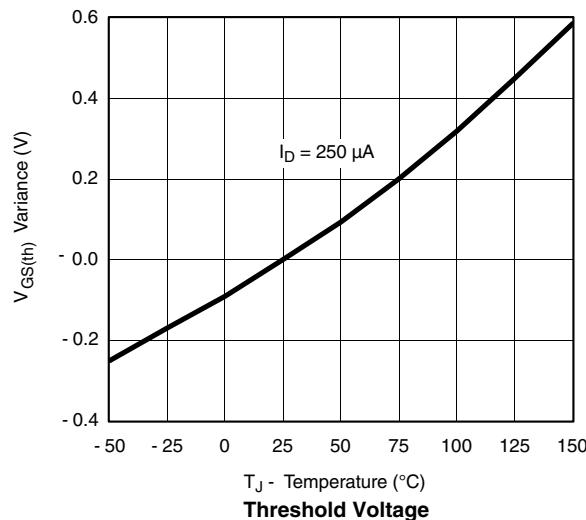
**TYPICAL CHARACTERISTICS**  $25^\circ\text{C}$ , unless otherwise noted

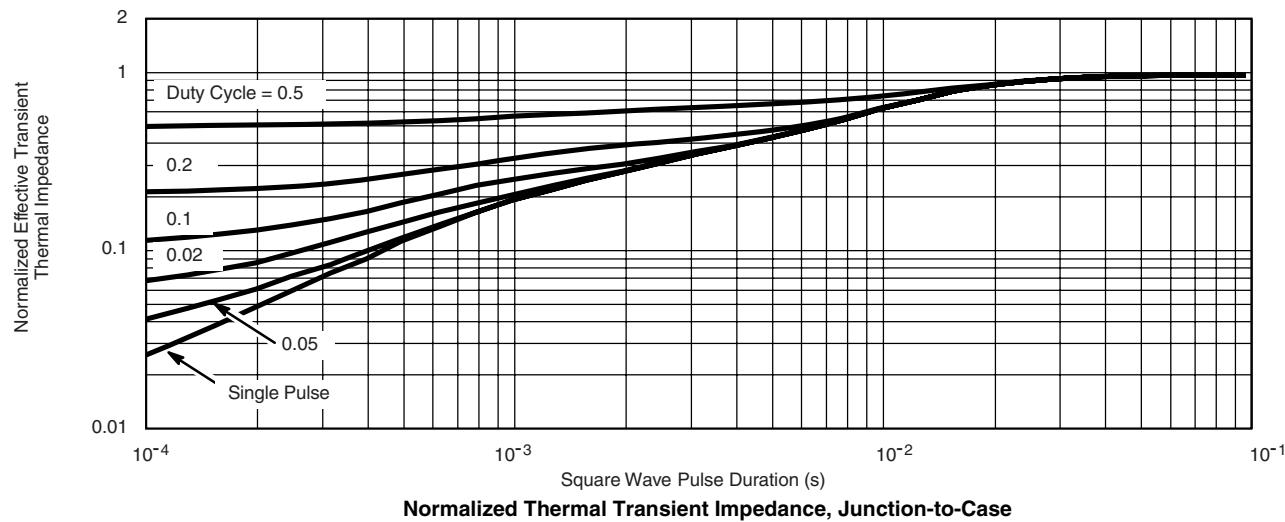


**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted


On-Resistance vs. Drain Current



**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted

**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted


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